

150V PNP HIGH VOLTAGE SWITCHING TRANSISTOR IN SOT89

Features

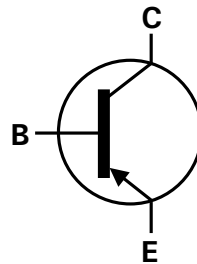
- $BV_{CEO} > -150V$
- $BV_{CEV} > -180V$
- $I_C = -700mA$ high Continuous Collector Current
- Low saturation voltage $V_{CE(sat)} < -300mV @ -100mA$
- Complementary NPN type: FCX495
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**
- **Qualified to AEC-Q101 Standards for High Reliability**

Mechanical Data

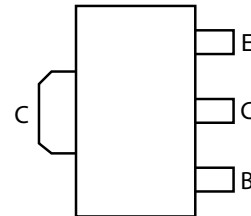
- Case: SOT89
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish - Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 ③
- Weight: 0.052 grams (Approximate)



Top View



Device Symbol



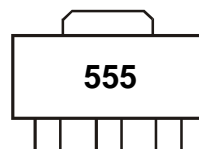
Top View
Pin Out

Ordering Information (Note 4)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|----------|---------|--------------------|-----------------|-------------------|
| FCX555TA | 555 | 7 | 12 | 1,000 |

- Notes:
1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
 4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



555 = Product Type Marking Code

Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Limit | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | -180 | V |
| Collector-Emitter Voltage | V _{CEV} | -180 | V |
| Collector-Emitter Voltage | V _{CEO} | -150 | V |
| Emitter-Base Voltage | V _{EBO} | -7 | V |
| Continuous Collector Current | I _C | -0.7 | A |
| Peak Pulse Current | I _{CM} | -2 | A |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

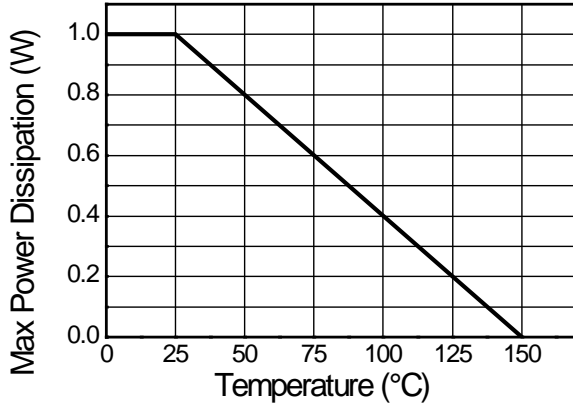
| Characteristic | Symbol | Value | Unit |
|---|-----------------------------------|-------------|------|
| Power Dissipation | P _D | (Note 5) | 1 |
| | | (Note 6) | 1.5 |
| | | (Note 7) | 2.1 |
| Thermal Resistance, Junction to Ambient Air | R _{θJA} | (Note 5) | 125 |
| | | (Note 6) | 83 |
| | | (Note 7) | 60 |
| Thermal Resistance, Junction to Lead | R _{θJL} | 10.01 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -65 to +150 | °C |

ESD Ratings (Note 9)

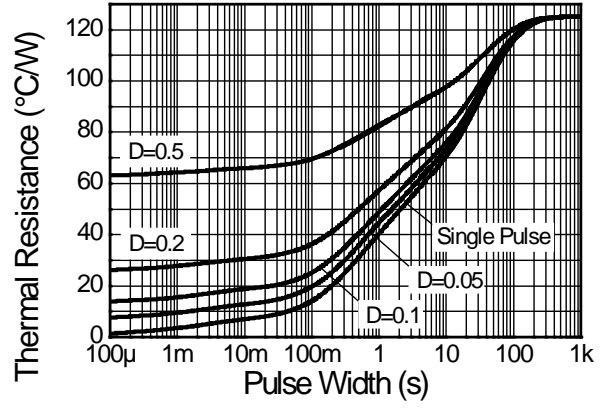
| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|---------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | ≥ 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | ≥ 400 | V | C |

- Notes:
5. For a device mounted with the exposed collector pad on 15mm x 15mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
 6. Same as note (5), except the device is mounted on 25mm x 25mm 1oz copper.
 7. Same as note (5), except the device is mounted on 50mm x 50mm 1oz copper.
 8. Thermal resistance from junction to solder-point (on the exposed collector pad).
 9. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

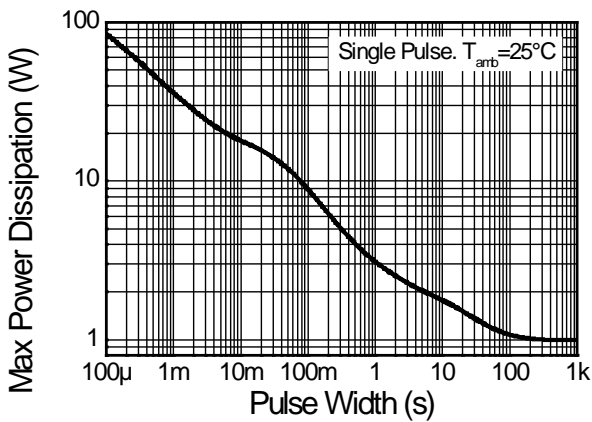
Thermal Characteristics and Derating Information



Derating Curve



Transient Thermal Impedance



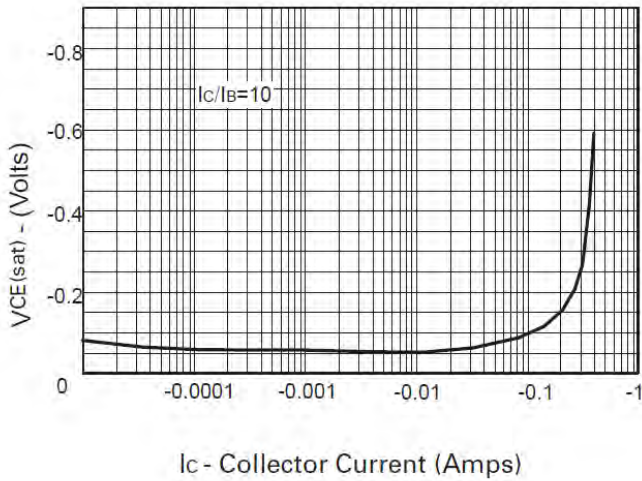
Pulse Power Dissipation

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

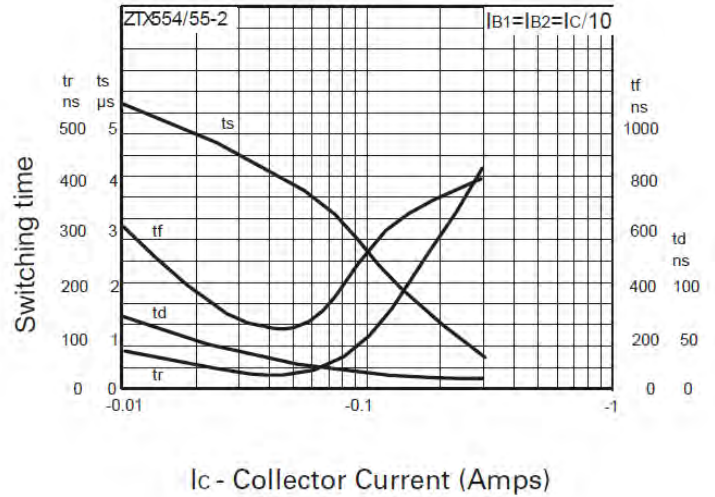
| Characteristic | Symbol | Min | Typ | Max | Unit | Test Condition |
|--|----------------------|------|------|-------|------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | -180 | — | — | V | I _C = -100μA |
| Collector-Emitter Breakdown Voltage | BV _{CEV} | -180 | — | — | V | I _C = -1μA, -0.3V < V _{BE} < 1V |
| Collector-Emitter Breakdown Voltage | BV _{CER} | -180 | — | — | V | I _C = -1μA, R _B ≤ 1kΩ |
| Collector-Emitter Breakdown Voltage (Note 10) | BV _{CEO} | -150 | — | — | V | I _C = -1mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | -7 | -8.1 | — | V | I _E = -100μA |
| Collector Cutoff Current | I _{CBO} | — | <1 | -20 | nA | V _{CB} = -144V |
| | | — | - | -10 | μA | V _{CB} = -144V, T _A = +100°C |
| Emitter Cutoff Current | I _{EBO} | — | <1 | -20 | nA | V _{EB} = -6V |
| DC current transfer Static ratio (Note 10) | h _{FE} | 100 | — | — | — | I _C = -10mA, V _{CE} = -5V |
| | | 100 | — | 300 | — | I _C = -100mA, V _{CE} = -5V |
| Collector-Emitter Saturation Voltage (Note 10) | V _{CE(sat)} | — | — | -300 | mV | I _C = -100mA, I _B = -10mA |
| | | — | — | -400 | mV | I _C = -250mA, I _B = -25mA |
| Base-Emitter Saturation Voltage (Note 10) | V _{BE(sat)} | — | — | -1000 | mV | I _C = -250mA, I _B = -25mA |
| Base-Emitter Turn-on Voltage (Note 10) | V _{BE(on)} | — | — | -950 | mV | I _C = -250mA, V _{CE} = -5V |
| Transitional Frequency | f _T | — | 100 | — | MHz | I _E = -50mA, V _{CE} = -10V f = 100MHz |
| Output capacitance | C _{obo} | — | — | 10 | pF | V _{CB} = -10V, f = 1MHz, |

Note: 10. Measured under pulsed conditions. Pulse width ≤ 300μs. Duty cycle ≤ 2%.

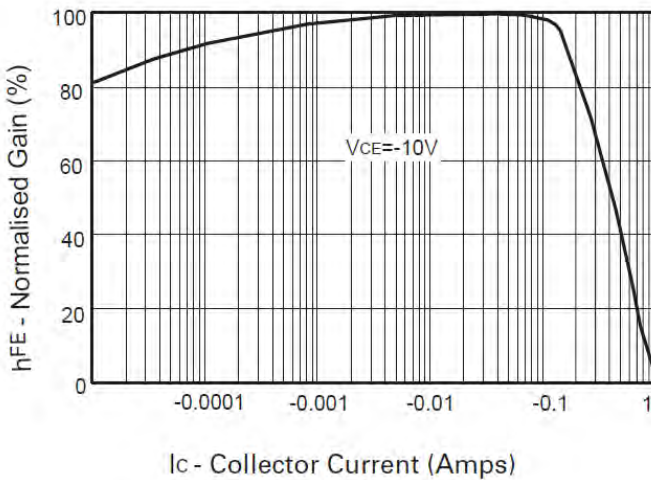
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



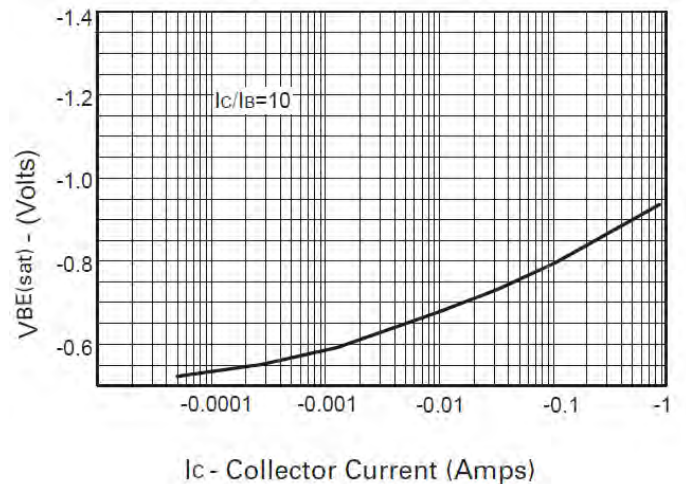
$V_{CE(sat)}$ v I_C



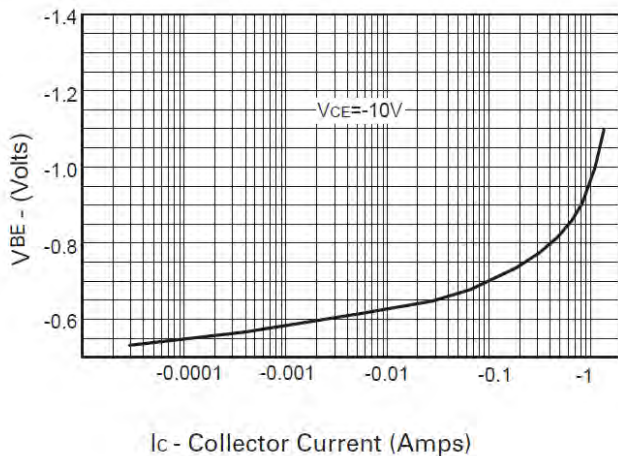
Switching Speeds



h_{FE} v I_C



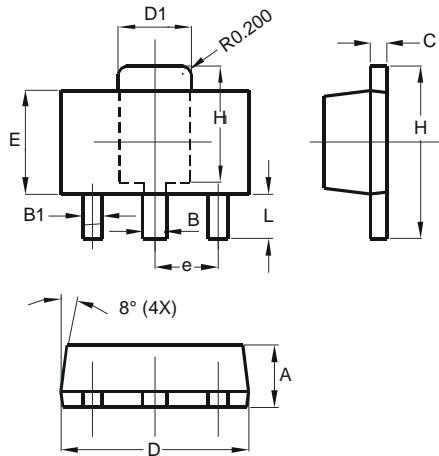
$V_{BE(sat)}$ v I_C



$V_{BE(on)}$ v I_C

Package Outline Dimensions

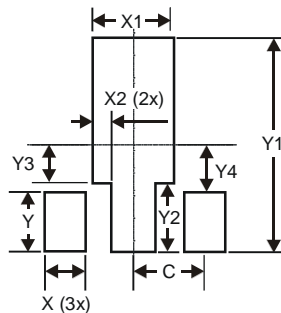
Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.



| SOT89 | | |
|----------------------|----------|------|
| Dim | Min | Max |
| A | 1.40 | 1.60 |
| B | 0.44 | 0.62 |
| B1 | 0.35 | 0.54 |
| C | 0.35 | 0.44 |
| D | 4.40 | 4.60 |
| D1 | 1.62 | 1.83 |
| E | 2.29 | 2.60 |
| e | 1.50 Typ | |
| H | 3.94 | 4.25 |
| H1 | 2.63 | 2.93 |
| L | 0.89 | 1.20 |
| All Dimensions in mm | | |

Suggested Pad Layout

Please see AP02001 at <http://www.diodes.com/datasheets/ap02001.pdf> for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| X | 0.900 |
| X1 | 1.733 |
| X2 | 0.416 |
| Y | 1.300 |
| Y1 | 4.600 |
| Y2 | 1.475 |
| Y3 | 0.950 |
| Y4 | 1.125 |
| C | 1.500 |

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.

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